

# TOPCon 182 ZBB

## 182 Mono-Crystalline Bifacial Solar Cell

### Test Efficiency



**25.4-26.3%**

### Temperature Coefficients

Temperature coefficient of Pmax	-0.35%/K
Temperature coefficient of Vocmax	-0.30%/K
Temperature coefficient of Iscmax	+0.048%/K

### Product Characteristics



#### High Efficiency

TOPCon cells have a thin film of tunneling oxide silicon and a layer of heavily doped polycrystalline silicon, greatly reducing the recombination velocity of the back surface field and the recombination at the rear metalized contacts, gaining a high Voc of more than 700 mV. They have an efficiency several percentage points higher than that of



#### Low Attenuation Rate

As N-type silicon wafers are doped with phosphorus elements, no boron-oxygen pairs are formed to result in a recombination center and further electron capture losses, making the light-induced attenuation almost zero. The attenuation rate of TOPCon components is 1% in the first year, 50% that of PERC cells, and attenuation is 0.4% per year thereafter (which is about 0.45% for PERC).



#### Low Temperature Coefficient

The temperature coefficient of P-type components is  $-0.34\%/^{\circ}\text{C}$ , while that of N-type TOPCon components is as low as  $-0.30\%/^{\circ}\text{C}$ , making the latter outstanding in terms of generation capacity in high-temperature environments.



#### High Bifaciality Factor

TOPCon cells have a bifaciality factor of up to 85%, and the figure is only about 70% for PERC ones. Large-scale bases usually have a high ground reflectivity (usually 30%) due to vastness. Therefore, H-type components with a high bifaciality factor will deliver higher power generation gains.

